

DRD4890L15

Rectifier Diode

DS2667-1 February 2018 (LN35170)

Replaces DS4179-6.0 August 2001 - Datasheet DNB63

FEATURES

- Double Side Cooling
- High Surge Capability

KEY PARAMETERS

| V_{RRM} | 1500V |
|--------------------|-------|
| I _{F(AV)} | 5794A |
| I _{FSM} | 57kA |

VOLTAGE RATINGS

| Part and Ordering Number | Repetitive Peak Voltages V _{RRM} V | Conditions |
|--|--|----------------------------|
| DRD4890L15 DRD4890L14 DRD4890L12 | 1500 1400 1200 | $V_{RSM} = V_{RRM} + 100V$ |

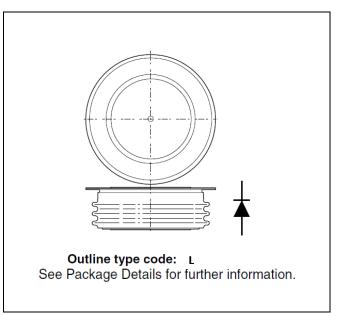


Fig. 1 Package outline

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DRD4890L14 for a 1400V device



CURRENT RATINGS

$T_{case} = 75$ °C unless stated otherwise

| Symbol | Parameter | Test Conditions | Max. | Units | | |
|---------------------|--------------------------------------|--------------------------|------|-------|--|--|
| Double Si | Double Side Cooled | | | | | |
| $I_{F(AV)}$ | Mean forward current | Half wave resistive load | 5794 | А | | |
| I _{F(RMS)} | RMS value | - | 9101 | А | | |
| I _F | Continuous (direct) on-state current | - | 7934 | А | | |
| Single Sid | le Cooled (Anode side) | , | 1 | l | | |
| $I_{F(AV)}$ | Mean forward current | Half wave resistive load | 4230 | А | | |
| I _{F(RMS)} | RMS value | - | 6645 | А | | |
| I _F | Continuous (direct) on-state current | • | 5468 | Α | | |

T_{case} = 100°C unless stated otherwise

| Symbol | Parameter | Test Conditions | Max. | Units |
|---------------------|--------------------------------------|--------------------------|------|-------|
| Double Si | de Cooled | 1 | | |
| $I_{F(AV)}$ | Mean forward current | Half wave resistive load | 4890 | А |
| I _{F(RMS)} | RMS value | - | 7681 | А |
| I _F | Continuous (direct) on-state current | - | 6600 | Α |
| Single Sid | de Cooled (Anode side) | | | |
| I _{F(AV)} | Mean forward current | Half wave resistive load | 3540 | Α |
| I _{F(RMS)} | RMS value | - | 5560 | Α |
| I _F | Continuous (direct) on-state current | - | 4500 | А |



SURGE RATINGS

| Symbol | Parameter | Test Conditions | Max. | Units |
|------------------|---|---|------|-------------------|
| I _{FSM} | Surge (non-repetitive) on-state current | 10ms half sine, T _{case} = 190°C | 52.0 | kA |
| l ² t | I ² t for fusing | $V_R = 50\% V_{RRM} - \frac{1}{4}$ sine | 13.5 | MA ² s |
| I _{FSM} | Surge (non-repetitive) on-state current | 10ms half sine, T _{case} = 190°C | 57.0 | kA |
| l ² t | I ² t for fusing | $V_R = 0$ | 16.2 | MA ² s |

THERMAL AND MECHANICAL RATINGS

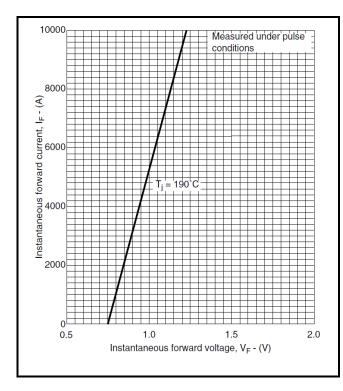
| Symbol | Parameter | Test Conditions | | Min. | Max. | Units |
|----------------------|---------------------------------------|--------------------------|-------------|------|-------|-------|
| R _{th(j-c)} | Thermal resistance – junction to case | Double side cooled | DC | - | 0.013 | °C/W |
| | | Single side cooled | Anode DC | - | 0.025 | °C/W |
| | | | Cathode DC | - | 0.027 | °C/W |
| R _{th(c-h)} | Thermal resistance – case to heatsink | Clamping force 43kN | Double side | - | 0.003 | °C/W |
| | | (with mounting compound) | Single side | - | 0.006 | °C/W |
| T _{vj} | Virtual junction temperature | On-state (conducting) | • | - | 200 | °C |
| | | Reverse (blocking) | | - | 190 | °C |
| T _{stg} | Storage temperature range | | | -55 | 190 | °C |
| Fm | Clamping force | | | 40.0 | 48.0 | kN |



CHARACTERISTICS

| Symbol | Parameter | Test Conditions | Тур. | Max. | Units |
|-----------------|-------------------------------|---|------|-------|-------|
| V_{FM} | Forward voltage | At 3000A peak, T _{case} = 25°C | - | 1.05 | V |
| I _{RM} | Peak reverse current | At V _{RRM} , T _{case} = 190°C | - | 60 | mA |
| Qs | Total stored charge | I _F = 2000A, dI _{RR} /dt =50A/μs T _{case} = 175°C, V _R =100V | - | 4000 | μC |
| I _{rr} | Peak reverse recovery current | | - | 600 | Α |
| t _{rr} | Reverse recovery time | | | 20 | us |
| V_{TO} | Threshold voltage | At T _{vj} = 190°C | - | 0.75 | V |
| r _T | Slope resistance | At T _{vj} = 190°C | - | 0.046 | mΩ |

CURVES



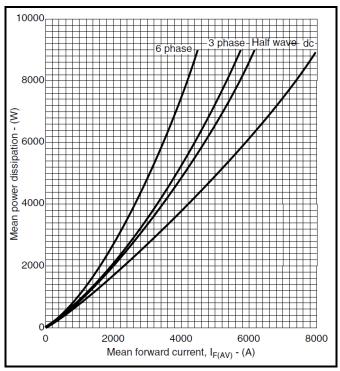


Fig.2 Maximum & minimum on-state characteristics

Fig.3 Dissipation curves

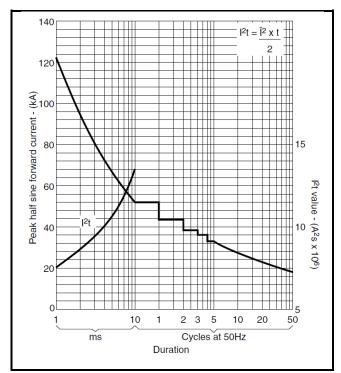
 V_{TM} EQUATION

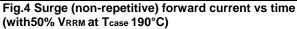
 $V_{TM} = A + Bln (I_T) + C.I_T + D.\sqrt{I_T}$

Where A = 0.517184 B = 0.035583 $C = 4.94 \times 10^5$ D = -0.0011

these values are valid for $T_j = 190$ °C for $I_F 500$ A to 10000A







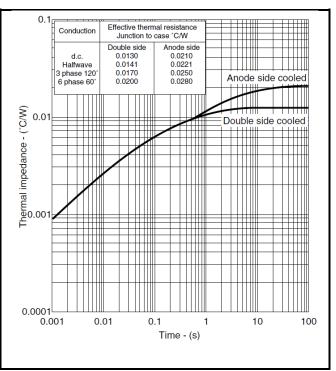
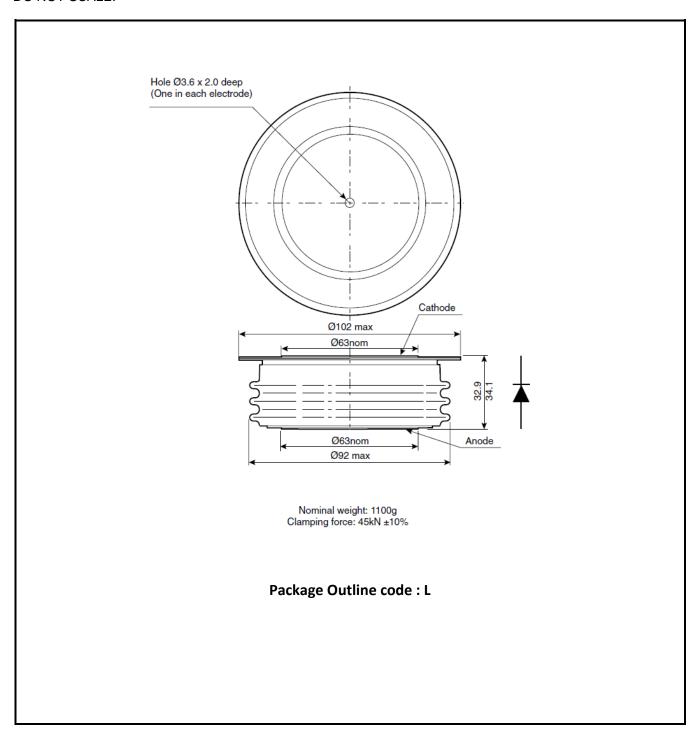


Fig.5 Maximum (limit) transient thermal impedancejunction to case



PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Note:

Some packages may be supplied with gate and or tags.



IMPORTANT INFORMATION:

This publication is provided for information only and not for resale.

The products and information in this publication are intended for use by appropriately trained technical personnel.

Due to the diversity of product applications, the information contained herein is provided as a general guide only and does not constitute any guarantee of suitability for use in a specific application. The user must evaluate the suitability of the product and the completeness of the product data for the application. The user is responsible for product selection and ensuring all safety and any warning requirements are met. Should additional product information be needed please contact Customer Service.

Although we have endeavoured to carefully compile the information in this publication it may contain inaccuracies or typographical errors. The information is provided without any warranty or guarantee of any kind.

This publication is an uncontrolled document and is subject to change without notice. When referring to it please ensure that it is the most up to date version and has not been superseded.

The products are not intended for use in applications where a failure or malfunction may cause loss of life, injury or damage to property. The user must ensure that appropriate safety precautions are taken to prevent or mitigate the consequences of a product failure or malfunction.

The products must not be touched when operating because there is a danger of electrocution or severe burning. Always use protective safety equipment such as appropriate shields for the product and wear safety glasses. Even when disconnected any electric charge remaining in the product must be discharged and allowed to cool before safe handling using protective gloves.

Extended exposure to conditions outside the product ratings may affect reliability leading to premature product failure. Use outside the product ratings is likely to cause permanent damage to the product. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture, a large current to flow or high voltage arcing, resulting in fire or explosion. Appropriate application design and safety precautions should always be followed to protect persons and property.

Product Status & Product Ordering:

We annotate datasheets in the top right hand corner of the front page, to indicate product status if it is not yet fully approved for production. The annotations are as follows:-

Target Information: This is the most tentative form of information and represents a very preliminary specification.

No actual design work on the product has been started.

Preliminary Information:

The product design is complete and final characterisation for volume production is in progress. The datasheet represents the product as it is now understood but details may change.

No Annotation:

The product design is complete and final characterisation for volume production is in progress. The datasheet represents the product as it is now understood but details may change.

The product has been approved for production and unless otherwise notified by Dynex any

The product has been approved for production and unless otherwise notified by Dynex any product ordered will be supplied to the current version of the data sheet prevailing at the

time of our order acknowledgement.

All products and materials are sold and services provided subject to Dynex's conditions of sale, which are available on request.

Any brand names and product names used in this publication are trademarks, registered trademarks or trade names of their respective owners.

HEADQUARTERS OPERATIONS

DYNEX SEMICONDUCTOR LIMITED Doddington Road, Lincoln, Lincolnshire, LN6 3LF

United Kingdom.

Phone: +44 (0) 1522 500500 Fax: +44 (0) 1522 500550 Web: http://www.dynexsemi.com

CUSTOMER SERVICE

Phone: +44 (0) 1522 502753 / 502901 Fax: +44 (0) 1522 500020

e-mail: power_solutions@dynexsemi.com

© Dynex Semiconductor Ltd. Technical Documentation – Not for resale.